



5SDA 07D3806

Old part no. DA 807-680-38

Avalanche Diode

Properties

- low on-state voltage
- avalanche reverse characteristics
- high operational reliability
- suitable for parallel operation

Key Parameters

V_{RRM}	=	3 800	V
I_{FAVm}	=	790	A
I_{FSM}	=	7 600	A
V_{TO}	=	1.010	V
r_T	=	0.720	m Ω

Types

	V_{RRM}
5SDA 07D3806	3 800 V
Conditions:	$T_j = -40 \div 160$ °C, half sine waveform, $f = 50$ Hz

Mechanical Data

F_m	Mounting force	11 ± 1 kN
m	Weight	0.23 kg
D_s	Surface creepage distance	30 mm
D_a	Air strike distance	20.5 mm

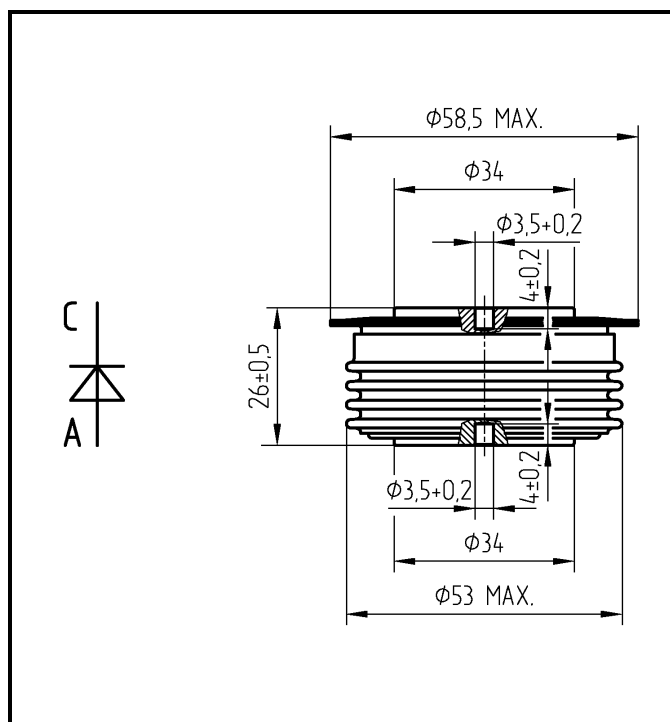


Fig. 1 Case



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Maximum Ratings		Maximum Limits	Unit	
V_{RRM}	Repetitive peak reverse voltage $T_j = -40 \div 160 \text{ }^\circ\text{C}$	3 800	V	
I_{FAVm}	Average forward current $T_c = 85 \text{ }^\circ\text{C}$	790	A	
I_{FRMS}	RMS forward current $T_c = 85 \text{ }^\circ\text{C}$	1 240	A	
I_{RRM}	Repetitive reverse current $V_R = V_{RRM}$	50	mA	
I_{FSM}	Non repetitive peak surge current $V_R = 0 \text{ V, half sine pulse}$	$t_p = 8.3 \text{ ms}$	8 100	A
		$t_p = 10 \text{ ms}$	7 600	A
I^2t	Limiting load integral $V_R = 0 \text{ V, half sine pulse}$	$t_p = 8.3 \text{ ms}$	270 000	A²s
		$t_p = 10 \text{ ms}$	289 000	A²s
P_{RSM}	Maximum avalanche power dissipation <i>rectangular pulse 20 μs</i>	50	kW	
$T_{jmin} - T_{jmax}$	Operating temperature range	-40 \div 160	$^\circ\text{C}$	
T_{STG}	Storage temperature range	-40 \div 160	$^\circ\text{C}$	

Unless otherwise specified $T_j = 160 \text{ }^\circ\text{C}$

Characteristics		Value			Unit
		<i>min</i>	<i>typ</i>	<i>max</i>	
V_{T0}	Threshold voltage			1.010	V
r_T	Forward slope resistance $I_F = 800 \div 2400 \text{ A}$			0.720	mΩ
V_{FM}	Maximum forward voltage $I_{FM} = 1\,800 \text{ A}$			2.310	V
Q_{rr}	Recovered charge $V_R = 100 \text{ V, } I_{FM} = 1\,000 \text{ A, } di_F/dt = -5 \text{ A}/\mu\text{s}$		1 350		μC

Unless otherwise specified $T_j = 160 \text{ }^\circ\text{C}$

Thermal Parameters		Value	Unit
R_{thjc}	Thermal resistance junction to case	<i>double side cooling</i>	40
		<i>anode side cooling</i>	65
		<i>cathode side cooling</i>	104
R_{thch}	Thermal resistance case to heatsink	<i>double side cooling</i>	10
		<i>single side cooling</i>	20

Transient Thermal Impedance

Analytical function for transient thermal impedance

$$Z_{thjc} = \sum_{i=1}^4 R_i (1 - \exp(-t / \tau_i))$$

Conditions:

$F_m = 11 \pm 1$ kN, Double side cooled

i	1	2	3	4
R_i (K/kW)	20.95	10.57	7.15	1.33
τ_i (s)	0.396	0.072	0.009	0.0044

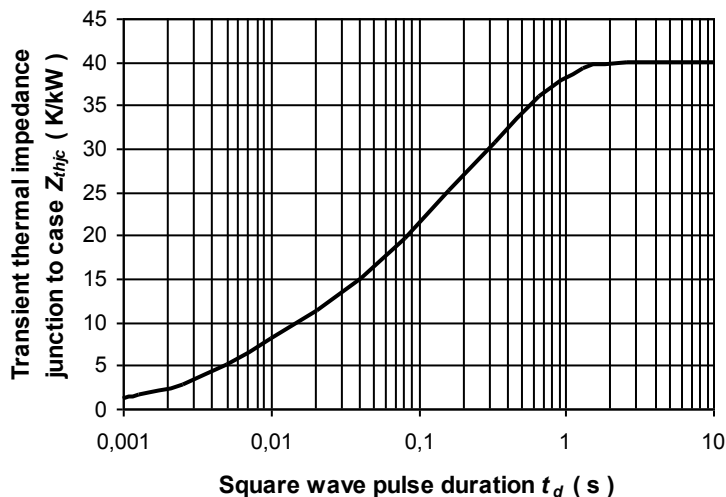


Fig. 2 Transient thermal impedance junction to case

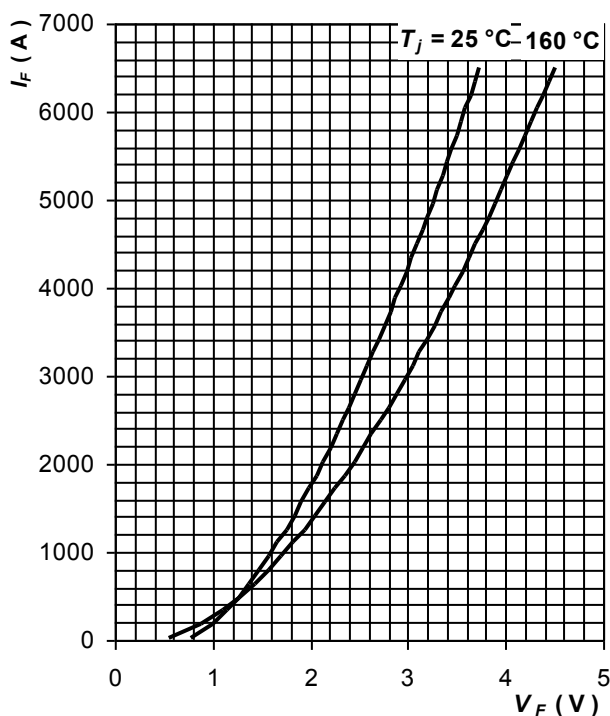


Fig. 3 Maximum forward voltage drop characteristics

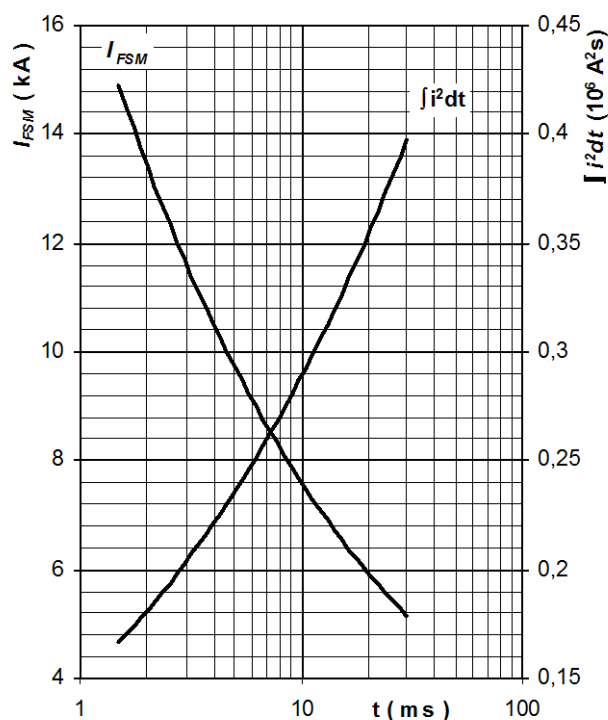


Fig. 4 Surge forward current vs. pulse length, half sine wave, single pulse, $V_R = 0$ V, $T_j = T_{jmax}$

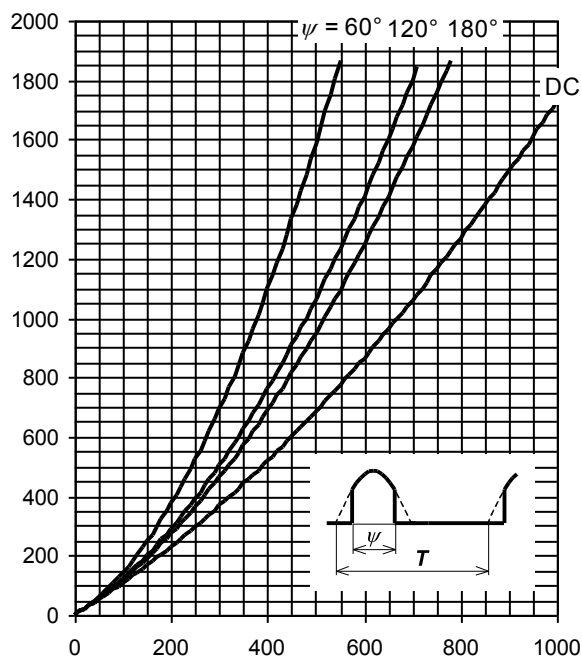


Fig. 5 Forward power loss vs. average forward current, sine waveform, $f = 50 \text{ Hz}$, $T = 1/f$

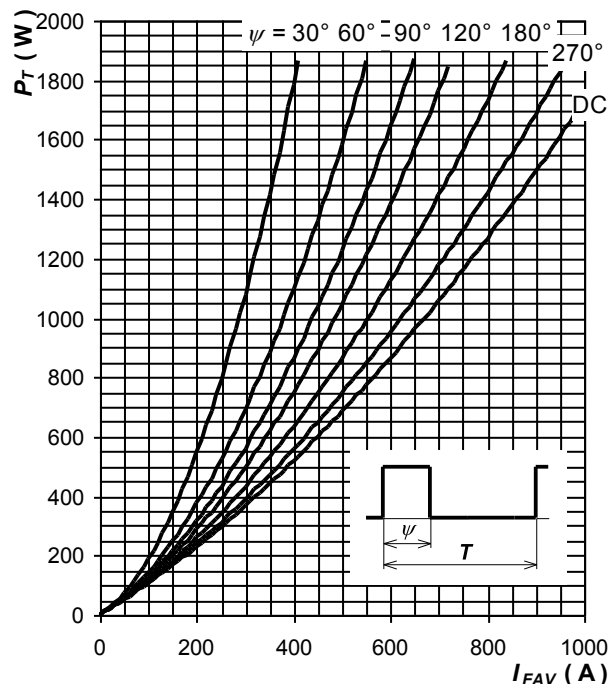


Fig. 6 Forward power loss vs. average forward current, square waveform, $f = 50 \text{ Hz}$, $T = 1/f$

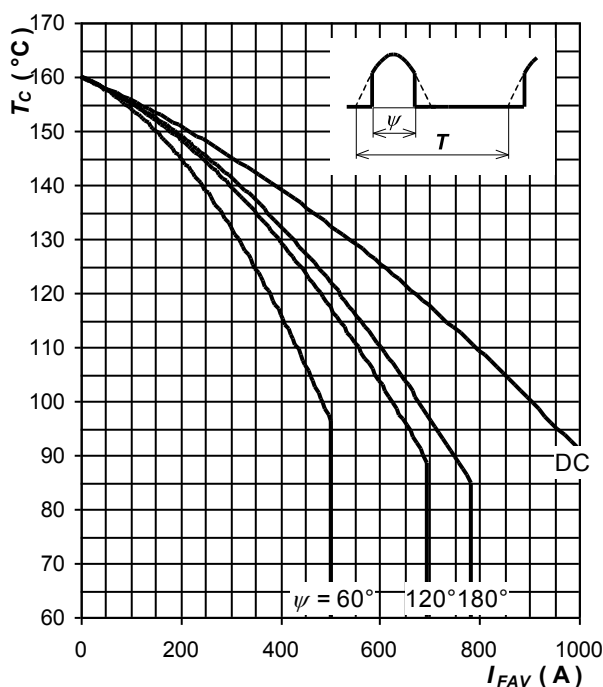


Fig. 7 Max. case temperature vs. aver. forward current, sine waveform, $f = 50 \text{ Hz}$, $T = 1/f$

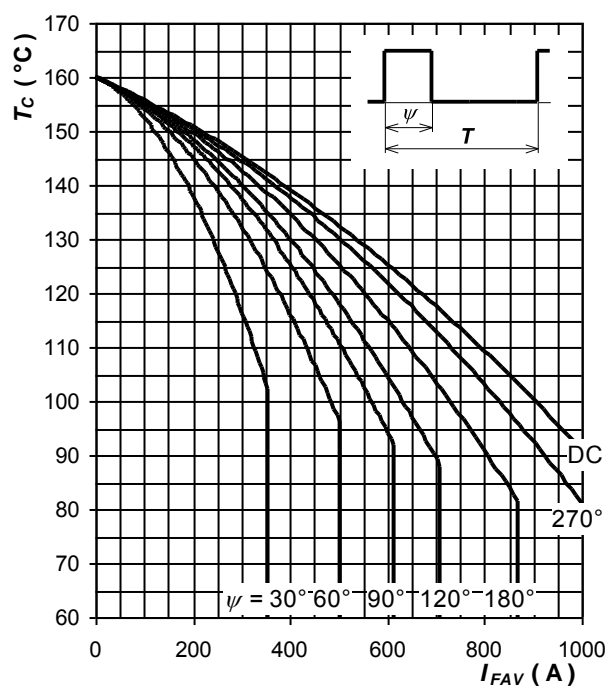


Fig. 8 Max. case temperature vs. aver. forward current, square waveform, $f = 50 \text{ Hz}$, $T = 1/f$

Notes: